ON Semiconductor

Is Now



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Power MOSFET 60 Amps, 60 Volts N-Channel D²PAK, TO-220

Features

- Low R_{DS(on)}
- High Current Capability
- Avalanche Energy Specified
- These are Pb-Free Devices

Applications

- LED Lighting and LED Backlight Drivers
- DC-DC Converters
- DC Motor Drivers
- Power Supplies Secondary Side Synchronous Rectification

MAXIMUM RATINGS (T_J = 25°C Unless otherwise specified)

Para	Symbol	Value	Unit		
Drain-to-Source Voltage			V_{DSS}	60	V
Gate-to-Source Voltage	ge – Conti	nuous	V _{GS}	±20	V
Gate-to-Source Voltage - Nonrepetitive (Tp < 10 µs)			V_{GS}	±30	V
Continuous Drain	Steady State	T _C = 25°C	I _D	60	Α
Current R _{0JC} (Note 1)	State	T _C = 100°C		44	
Power Dissipation R ₀ JC (Note 1)	Steady State	T _C = 25°C	P _D	125	W
Pulsed Drain Current	Pulsed Drain Current $t_p = 10 \mu s$			155	Α
Operating and Storage Temperature Range			T _J , T _{stg}	–55 to 175	°C
Source Current (Body Diode)			Is	60	Α
Single Pulse Drain-to-Source Avalanche Energy – Starting $T_J = 25^{\circ}C$ ($V_{DD} = 50 \ V_{dc}, \ V_{GS} = 10 \ V_{dc}, \ I_{L(pk)} = 60 \ A, L = 0.1 \ mH, \ R_G = 25 \ \Omega)$			E _{AS}	180	mJ
Lead Temperature for Soldering Purposes, 1/8" from Case for 10 Seconds			T _L	260	°C

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Max	Unit
Junction-to-Case (Drain) Steady State (Note 1)	$R_{\theta JC}$	1.2	°C/W
(Note 1)	$R_{\theta JA}$	43.2	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

 Surface mounted on FR4 board using 1 sq in pad size, (Cu Area 1.127 sq in [1 oz] including traces).

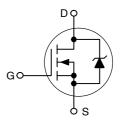


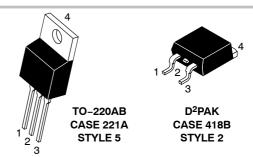
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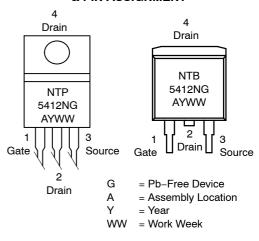
V _{(BR)DSS}	R _{DS(ON)} MAX	I _D MAX (Note 1)		
60 V	14 mΩ @ 10 V	60 A		

N-Channel





MARKING DIAGRAM & PIN ASSIGNMENT



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS ($T_J = 25$ °C Unless otherwise specified)

Characteristics	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS	•			•		-	•
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V _{DS} = 0 V,	I _D = 250 μA	60			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /T _J				54.6		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V	T _J = 25°C			1.0	μΑ
		$V_{DS} = 60 \text{ V}$	T _J = 150°C			100	1
Gate-Body Leakage Current	I _{GSS}	V _{DS} = 0 V, V	′ _{GS} = ±20 V			±100	nA
ON CHARACTERISTICS (Note 2)	•			•		-	•
Gate Threshold Voltage	V _{GS(th)}	$V_{GS} = V_{DS}$	I _D = 250 μA	2.0	3.3	4.0	V
Negative Threshold Temperature Coefficient	V _{GS(th)} /T _J				6.4		mV/°C
Drain-to-Source On Voltage	V _{DS(on)}	V _{GS} = 10 \	/, I _D = 60 A		0.7	1.2	V
		V _{GS} = 10 V, I _D	= 30 A, 150°C		0.75		1
Static Drain-to-Source On-Resistance	R _{DS(on)}	V _{GS} = 10 \	/, I _D = 30 A		11.1	14	mΩ
Forward Transconductance	9FS	V _{GS} = 15 \	/, I _D = 30 A		58		S
CHARGES, CAPACITANCES & GATE RESIST	ANCE			1	•	•	•
Input Capacitance	C _{iss}	V _{DS} = 25 V	, V _{GS} = 0 V,		2325	3220	pF
Output Capacitance	C _{oss}	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1 MHz			440		
Transfer Capacitance	C _{rss}				170		
Total Gate Charge	Q _{G(TOT)}	V _{GS} = 0 V, V _{DS} = 48 V,			66	85	nC
Threshold Gate Charge	Q _{G(TH)}	I _D =	60 A		2.8		1
Gate-to-Source Charge	Q _{GS}	-			13.4		
Gate-to-Drain Charge	Q_{GD}				31		
SWITCHING CHARACTERISTICS, V _{GS} = 10 V	(Note 3)			1	•	•	•
Turn-On Delay Time	t _{d(on)}	V _{GS} = 10 V,	V _{DD} = 48 V,		14		ns
Rise Time	t _r	$I_{D} = 60 A,$	$R_G = 2.5 \Omega$		115		1
Turn-Off Delay Time	t _{d(off)}				41		
Fall Time	t _f	1			89		1
DRAIN-SOURCE DIODE CHARACTERISTICS				1	•	•	•
Forward Diode Voltage	V _{SD}	V _{GS} = 0 V	T _J = 25°C		1.0	1.2	V_{dc}
		I _S = 60 A	T _J = 125°C		0.9		1
Reverse Recovery Time	t _{rr}	$I_S = 60 \text{ A}_{dc}, V_{GS} = 0 \text{ V}_{dc},$ $dI_S/dt = 100 \text{ A}/\mu\text{s}$			75		ns
Charge Time	ta				54		1
Discharge Time	t _b				21		1
Reverse Recovery Stored Charge	Q _{RR}				96		nC

^{2.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%. 3. Switching characteristics are independent of operating junction temperatures.

TYPICAL PERFORMANCE CURVES

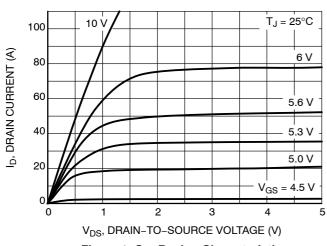


Figure 1. On-Region Characteristics

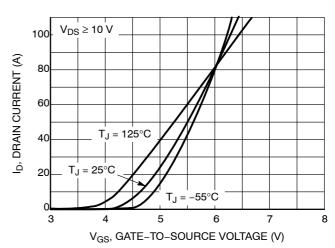


Figure 2. Transfer Characteristics

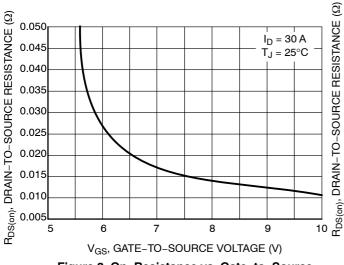


Figure 3. On-Resistance vs. Gate-to-Source Voltage

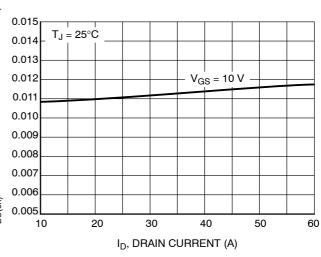


Figure 4. On-Resistance vs. Drain Current and Gate Voltage

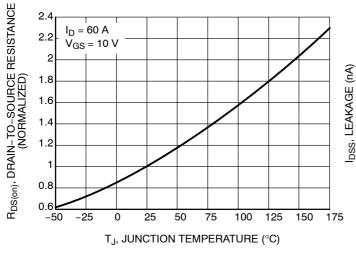


Figure 5. On–Resistance Variation with Temperature

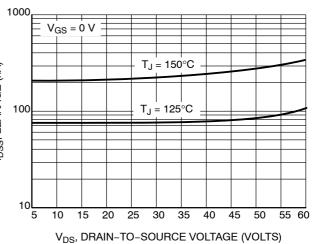
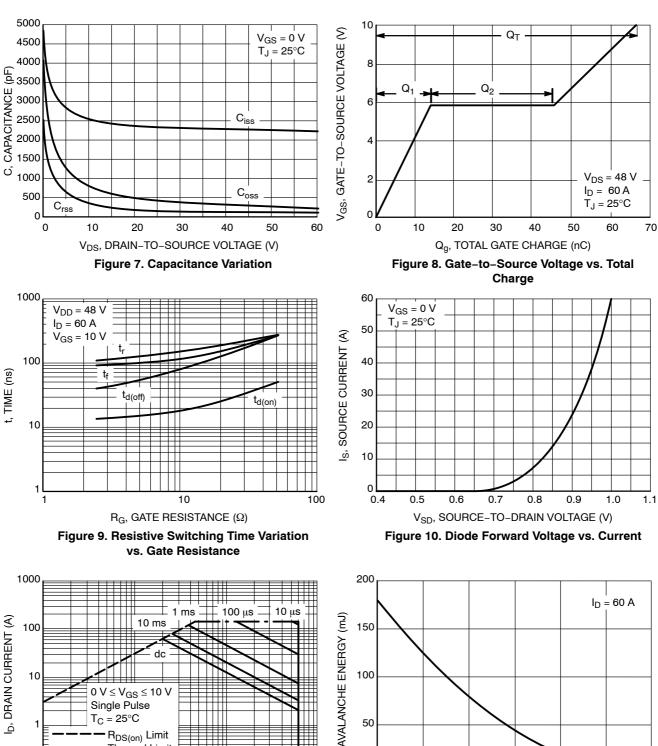


Figure 6. Drain-to-Source Leakage Current vs. Voltage

TYPICAL PERFORMANCE CURVES



 $0~V \leq V_{GS} \leq 10~V$ Single Pulse T_C = 25°C $R_{DS(on)}$ Limit Thermal Limit Package Limit 0.1 0.1 10 100 V_{DS}, DRAIN-TO-SOURCE VOLTAGE (V)

Figure 11. Maximum Rated Forward Biased Safe Operating Area

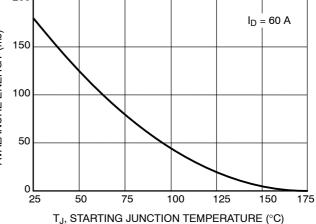


Figure 12. Maximum Avalanche Energy vs. **Starting Junction Temperature**

TYPICAL PERFORMANCE CURVES

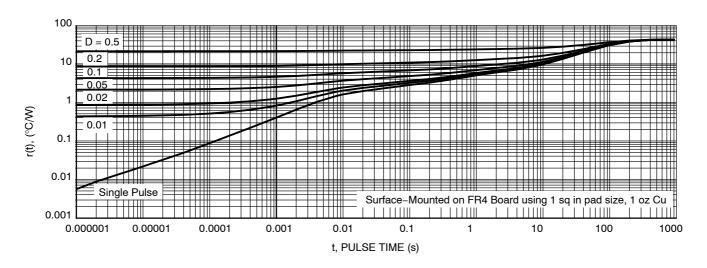


Figure 13. Thermal Response

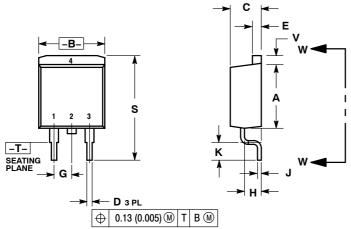
ORDERING INFORMATION

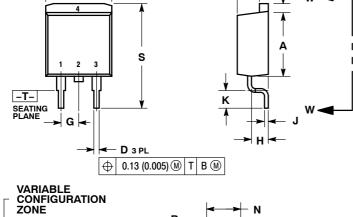
Device	Package	Shipping [†]
NTP5412NG	TO-220AB (Pb-Free)	50 Units / Rail
NTB5412NT4G	D ² PAK (Pb-Free)	800 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

D²PAK 3 CASE 418B-04 **ISSUE K**



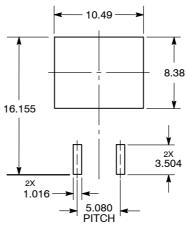


- NOTES:
 1. DIMENSIONING AND TOLERANCING
- PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. 418B-01 THRU 418B-03 OBSOLETE, NEW STANDARD 418B-04.

	INCHES		MILLIMETERS			
DIM	MIN	MAX	MIN	MAX		
Α	0.340	0.380	8.64	9.65		
В	0.380	0.405	9.65	10.29		
С	0.160	0.190	4.06	4.83		
D	0.020	0.035	0.51	0.89		
E	0.045	0.055	1.14	1.40		
F	0.310	0.350	7.87	8.89		
G	0.100	BSC	2.54 BSC			
Н	0.080	0.110	2.03	2.79		
J	0.018	0.025	0.46	0.64		
K	0.090	0.110	2.29	2.79		
L	0.052	0.072	1.32	1.83		
М	0.280	0.320	7.11	8.13		
N	0.197	0.197 REF		5.00 REF		
Р	0.079 REF		2.00 REF			
R	0.039 REF		0.99 REF			
S	0.575	0.625	14.60	15.88		
٧	0.045	0.055	1.14	1.40		

- STYLE 2: PIN 1. GATE 2. DRAIN 3. SOURCE 4. DRAIN
- R М VIEW W-W VIEW W-W VIEW W-W

SOLDERING FOOTPRINT*

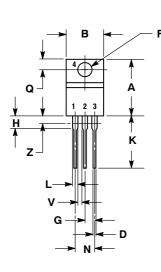


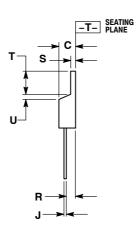
DIMENSIONS: MILLIMETERS

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AF**





- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.570	0.620	14.48	15.75	
В	0.380	0.405	9.66	10.28	
U	0.160	0.190	4.07	4.82	
D	0.025	0.035	0.64	0.88	
F	0.142	0.161	3.61	4.09	
G	0.095	0.105	2.42	2.66	
H	0.110	0.155	2.80	3.93	
7	0.014	0.025	0.36	0.64	
K	0.500	0.562	12.70	14.27	
L	0.045	0.060	1.15	1.52	
N	0.190	0.210	4.83	5.33	
ø	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.15	1.39	
T	0.235	0.255	5.97	6.47	
5	0.000	0.050	0.00	1.27	
٧	0.045		1.15		
Z		0.080		2.04	

STYLE 5:

PIN 1 GATE

- DRAIN 2.
- 3 SOURCE
- DRAIN

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